TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

TLP283,TLP283-4

PROGRAMMABLE CONTROLLERS

AC adapters for PDAs/ on-board power supplies I/O interface boards

TLP283 and TLP283-4 is a very small and thin coupler, suitable for surface mount assembly in applications such as on-board power supplies, programmable controllers.

TLP283 and TLP283-4 consist of photo transistor, optically coupled to a gallium arsenide infrared emitting diode.

Collector-Emitter Voltage : 100 V (MIN)

Current Transfer Ratio : 100% (MIN)@IF=1mA

1 Pulse delay time(Note 1): 100us(MAX)@IF=1mA,RL=10kΩ

Isolation Voltage : 2500 Vrms (MIN)

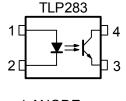
• UL Recognized : UL1577 , File No. E67349

Note 1:1 Pulse delay time = tON+tOFF

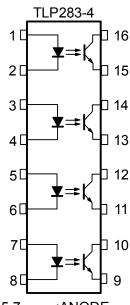
Unit in mm TLP283 TLP283 TLP283 TLP283 TLP283 TOSHIBA 11-3A1

Weight: 0.05 g (typ.)

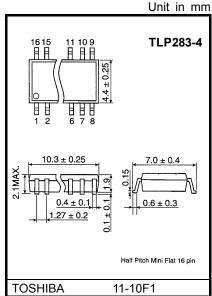
Pin Configuration (Top view)



1:ANODE 2:CATHODE 3:EMITTER 4:COLLECTOR



1,3,5,7 :ANODE 2,4,6,8 :CATHODE 9,11,13,15 :EMITTER 10,12,14,16 :COLLECTOR



Weight: 0.19 g (typ.)



Absolute Maximum Ratings (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RAT	UNIT	
	CHARACTERISTIC	STIVIBOL	TLP283	TLP283-4	UNIT
	Forward Current	lF	50		mA
	Forward Current Derating	ΔI _F /°C	-0.7 (Ta≥53°C)	-0.5 (Ta≥25°C)	mA /°C
LED	Pulse Forward Current	I _{FP}		1	Α
	Reverse Voltage	V _R		V	
	Junction Temperature	Tj	125		°C
	Collector-Emitter Voltage	V _{CEO}	10	V	
	Emitter-Collector Voltage	V _{ECO}	-	V	
R	Collector Current	IC	50		mA
DETECTOR	Collector Power Dissipation (1 Circuit)	PC	150	100	mW
D	Collector Power Dissipation Derating(Ta≥25°C) (1 Circuit)	ΔP _C /°C	-1.5	-1.0	mW /°C
	Junction Temperature	Tj	12	°C	
Оре	erating Temperature Range	T _{opr}	-55	°C	
Storage Temperature Range		T _{stg}	-55	°C	
Lea	d Soldering Temperature	T _{sol}	260 (10s)		°C
Total Package Power Dissipation (1 Circuit)		P _T	200	170	mW
Total Package Power Dissipation Derating (Ta≥25°C) (1 Circuit)		ΔP _T /°C	-2.0	-1.7	mW /°C
Isola	ation Voltage (Note2)	BVS	2500(AC,1min,R.H.≤60%)		Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note2) Device considered a two terminal device: LED side pins shorted together and DETECTOR side pins shorted together.

Individual Electrical Characteristics (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse Current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	C _T	V = 0, f = 1 MHz	1	30	_	pF
	Collector-Emitter Breakdown Voltage	V _(BR) CEO	I _C = 0.5 mA	100	_	_	٧
TOR	Emitter-Collector Breakdown Voltage	V _(BR) ECO	I _E = 0.1 mA	7	_	_	٧
DETECTOR	Collector Dark Current (Note3)	I _{CEO}	V _{CE} = 48 V, Ambient Light Below (100 &x)		0.01 (2)	0.1 (10)	μΑ
		ICEO	V _{CE} = 48 V, Ta = 85°C Ambient Light Below (100 &x)	_	2 (4)	50 (50)	μΑ
	Capacitance (Collector to Emitter)	C _{CE}	V = 0, f = 1 MHz	_	10	_	pF

(Note3) Because of the construction,leak current might be increased by ambient light.

Please use photocoupler with less ambient light.

TLP283,TLP283-4

Coupled Electrical Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I _C / I _F	I _F = 1 mA, V _{CE} = 5 V	100	_	400	%
Saturated CTR	I _C / I _{F (sat)}	IF = 1 mA, VCE = 0.4 V	50	_	_	%
Collector-Emitter Saturation Voltage	V _{CE} (sat)	I _C = 0.2 mA, I _F = 1 mA	_	0.2	0.4	V
Off-State Collector Current	I _{C (off)}	V _F = 0.7 V, V _{CE} = 48 V	_	_	10	μΑ

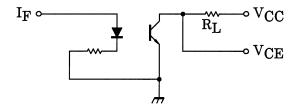
Isolation Characteristics (Ta = 25°C)

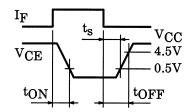
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	CS	V _S = 0 V, f = 1 MHz	_	8.0	_	pF
Isolation Resistance	R _S	V _S = 500 V, R.H.≤60%	5×10 ¹⁰	10 ¹⁴	_	Ω
	BVS	AC , 1 minute	2500	_	_	Vrms
Isolation Voltage		AC , 1 second,in OIL	_	5000	_	
		DC , 1 minute, in OIL	_	5000	_	Vdc

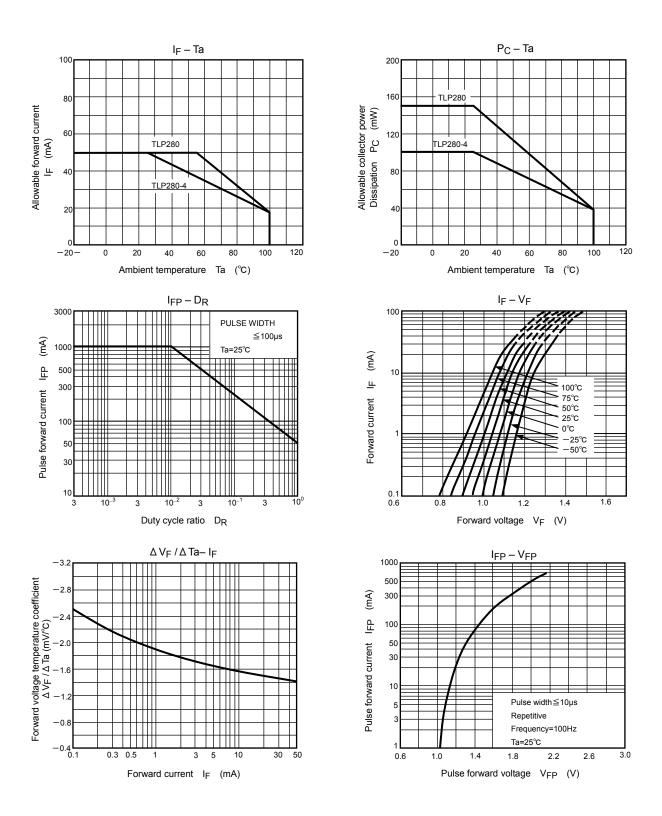
Switching Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-On Time	t _{ON}	V_{CC} = 5 V, IF = 1 mA R _L = 10kΩ	_	7.5	20	
Turn-Off Time	toff		_	70	90	μs
1 Pulse delay time	ton+ toff		_	80	100	

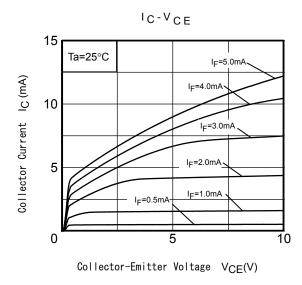
(Fig.1)SWITCHING TIME TEST CIRCUIT

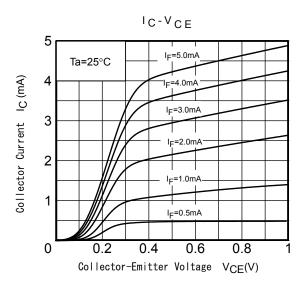


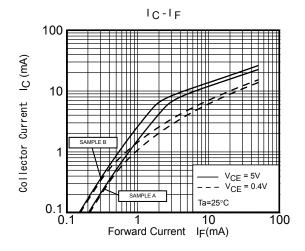


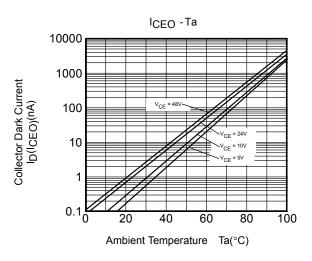


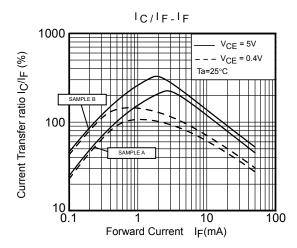
^{*:} The above graphs show typical characteristics.



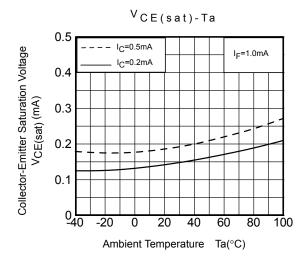


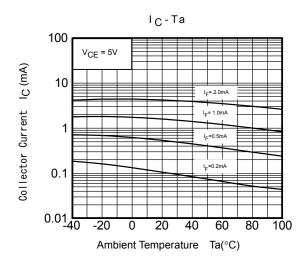


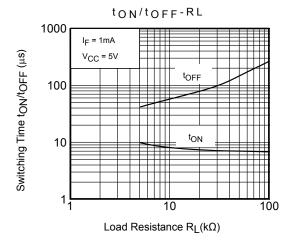


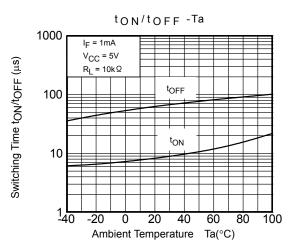


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